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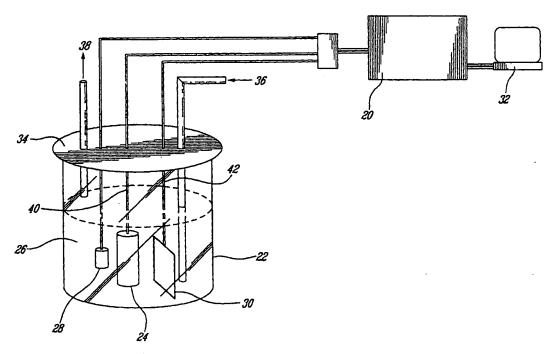
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[Continued on next page]

(54) Title: RADIOACTIVELY COATED DEVICE AND METHOD OF MAKING SAME FOR PREVENTING RESTENOSIS



(57) Abstract: The present invention relates to a rapid and reproducible electrochemical method leading to the production of radioactive angioplastic device such as stents, based on rapid and effective deposition or electrodeposition of charged radioactively coated molecule on oppositely charged surfaces (stainless or gold).

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Radioactively coated device and method of making same for preventing restensis

BACKGROUND OF THE INVENTION

5 (a) Field of the Invention

The invention relates to a radioactively coated device and to a method of making same by deposition of a radioisotope-containing molecule on the device.

(b) <u>Description of Prior Art</u>

Although coronary angioplasty procedure reduces 10 anginal symptoms, a high incidence of restenosis (30 to 40% within 6 months) is the "Achilles' heel" interventional cardiology. With over one coronary procedures performed annually around effect of 15 world, the economic restenosis substantial. It is estimated that an effective strategy to prevent restenosis, which would have to be applied after all coronary procedures, would represent a market of at least one billion U.S. dollars (US\$) 20 Pharmacological approaches to year. restenosis have failed to be effective and only coronary stenting procedure reduced restenosis rates BENESTENT (STRESS and trials). Stent deployment, however, frequently induces a new coronary occlusion known as in-stent restenosis. About 20% of stented 25 in-stent restenosis. patients develop To prevent occurrence of stenosis, new therapeutic strategies on the basis of ionizing radiation have recently been Intracoronary radiation proposed. therapy 30 reported to prevent intimal hyperplasia in various animal models (Raizner et al., Chap 3: 287-296,

Vascular Brachytherapy, Second Edition. Armonk, NY, 1999). In clinical development, endovascular radiotherapy (wire- and stent-based) in patients was reported to be safe and effective in preventing post-angioplasty al., restenosis (Condado et Circulation, 90(3):727-732, 1997; Teirstein et al., N. Engl. J. Med., 336(24):1697-1703, 1997; King et al., Circulation, 97:2025-2030, 1998; Waksman et al., Circulation, 101:1895-1898, 2000). To date, there is no consensus on the use of beta- or gamma-sources and 10 on the choice of medium-energy or higher beta energy (Coursey and Ravinder, Physics Today, vol. 53(4):25-30, 2000) to prevent restenosis. However, beta-emitter source (i.e., 32P, 90Y, 90Sr/Y) significantly reduces 15 operator exposure compared with previous trials with gamma-emitter isotopes (192 Ir). Compared to brachytherapy approach, stent-based radiotherapy acts by preventing both vessel shrinkage and excessive neointimal proliferation.

One of the main limitations of the extensive use of radioactive stent in interventional cardiology is the complex clinical prescription of the metallic prosthesis (diameter, length, type, etc.) associated with the choice of the radioisotope and the activity in function of the physical half-life. Regarding those specifications, the production of an active inventory of such device in a daily practice can be difficult and problematic. A major difficulty to overcome is the need to load any pre-manufactured stents with defined amounts of radioactivity at the time of use. Using stents that are preloaded by the

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manufacturer is not ideal because the stent specifications (specific radioactivity, length diameter, etc.) may differ from the need.

Häfeli et al. (Biomaterials 19:925-933, 1998) suggested a method for electrodepositing Rhenium (186Re 5 However, Häfeli et al. teach or ¹⁸⁸Re) on a stent. rhenium alone do not electroporate well by itself, and that they had to co-deposit the rhenium Again co-deposition with cobalt caused with cobalt. cracking and flaking of the deposited layer. To 10 overcome these problems, Häfeli et al. deposited over the layer of cobalt rhenium previously deposited a second layer of gold to overlay cobalt and thus prevent cracking. Häfeli et al. also teach that gold, being a noble metal compete with rhenium during the 15 deposition such that gold is deposited preferentially over rhenium.

Consequently it would be highly desirable to be provided with a strong and rapid deposition process of radioactivity emitting source (such oligonucleotide based) on the surface of a device such as a stent to prevent restenosis post-angioplasty, and The ability of ^{32}P that would not crack or flake. oligonucleotide to inhibit neointimal labeled hyperplasia was already demonstrated in an in vitro model (Fareh et al., Circulation, 99:1477-1484, 1999).

SUMMARY OF THE INVENTION

One aim of the present invention is to provide 30 a strong and rapid deposition process of radioactive

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molecule on the surface of an angioplastic device for preventing restenosis post-angioplasty.

In accordance with the present invention there is provided a method for depositing a charged molecule on an angioplastic device. This methods comprises the step of contacting the angioplastic device with a solution containing the charged molecule under suitable conditions for deposition of the charged molecule on the angioplastic device. The charged molecule is preferably a radioactive charged molecule.

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The deposition can be passive or active. By active deposition, it is meant to comprise electrodeposition.

In passive deposition, the angioplastic device has preferably stainless steel or gold on its surface. 15 gold surface, the charged molecule preferably comprises a thiol-containing group for attaching to the gold on the angioplastic device. For stainless steel, the surface is preferably coated with silicon oxyde (SiO₂₎ or silicon (Si) to be modified with 20 chemical or electrochemical treatments for its functionnalization. Stainless steel surface can be directly used for electrochemical functionnalization.

Also in accordance with the present invention, there is provided a method for immobilizing a charged molecule on an angioplastic device using passive deposition or electrodeposition. For the electric approach (electrodeposition), the method comprises the step of applying an electric potential difference between the angioplastic device and a solution

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containing the charged molecule, said charged molecule having a charge opposite to the electric potential difference and being thereby electrodeposited on the angioplastic device.

The electric potential difference can be made positive or negative, depending on the charge of the molecule to be coated on the device.

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Preferably the radioactive molecule comprises a β -Preferred β -emitters are selected from the group consisting of Antimony-124, Cesium-134, Cesium-10 137, Calcium-45, Calcium-47, Cerium 141, Chlorine-36, Cobalt-60, Europium-152, Gold-198, Hafnium-181, Holmiun-166, Iodine-131, Iridium-192, Iron-59, Lutetium-177, Mercury-203, Neodymium-147, Nickel-63, 15 Phosphorus-32, Phosphorus-33, Rhenium-186, Rhodium-Rubidium-86, Ruthenium-106, Samarium-153, Scandium-46, Silver-110m, Strontium-89, Strontium-90, Sulfur-35, Technetium-99, Terbium-160, Thulium-170, Tungsten-188, Yttrium-90 and Xenon-133.

When the electric potential difference applied is positive, the radioactive molecule is preferably selected from the group consisting of a radioactive DNA or an analog thereof, a radioactive RNA, a radioactive nucleotide, a radioactive oligonucleotide, radioactive H₂PO₄, radioactive diethylenetriaminepenta-acetic acid, and a radioactive polyanionic complex. More preferably the radioactive molecule is a radioactive oligonucleotide. The oligonucleotide is preferably a 8- to 35-mer oligonucleotide, more preferably a 8- to 20-mer oligonucleotide, and most preferably a 15-mer oligonucleotide. These molecules

form negative ions in solutions and are therefore attracted onto the angioplastic device.

When the electric potential difference applied is negative, molecules are preferably selected from the group consisting of conjugated cationic polypeptides, cationic peptides, dextran, polyamines and chitosan. These molecules are preferably radioactive molecules. These molecules form positive ions in solutions and are therefore attracted onto the angioplastic device.

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The angioplastic device may be for example a stent. Preferably the angioplastic device has a metallic surface, such as stainless steel, gold, tantalum, nickel and titanium or any alloy thereof.

The method of the present invention may further 15 comprise before the step of applying an electric potential difference, a step of surface cleaning of device with solvent, angioplastic a the electrochemical or argon-ion sputtering treatments for impurities the surface of 20 removing at said angioplastic device, or, after the step of applying an electric potential difference, a further step of rinsing the angioplastic device for removing free molecule at the surface of said angioplastic device.

In a preferred embodiment of the present invention, the surface of the angioplastic device is functionnalized for molecule coating. The angioplastic device may be functionnalized for example with a diazonium treatment.

30 Still in accordance with the present invention, there is provided an angioplastic device for

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preventing restenosis in a coronary and/or peripheral artery, said device comprising a radioactive charged molecule deposited on its surface.

Further in accordance with the present invention, there is provided a method for preventing restenosis in a coronary and/or peripheral artery comprising implanting an angioplastic device as defined above at a site of potential restenosis such as coronary and/or peripheral artery in a patient in need of such a treatment.

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The method of the present invention is rapid and allows obtaining a radioactively coated device, on which a radioisotope-containing molecule is effectively and uniformly deposited. No adverse effects of deposition treatment are observed in coated stent in vitro (mechanical and colorless properties) and in vivo (clotting, thrombogenicity). Strong and effective binding of ³²P-oligonucleotides on metallic surface was obtained.

Since the method of the present invention is rapid, it also allows to use simultaneously a stent with radiotherapy for preventing restenosis. It is now possible with the method of the present invention to attach a radioisotope-carrying molecule on a device such as a stent, according to a simple method. The simplicity of the method allows for that method to prepare a radioactively coated stent to be used for implantation just moments after its preparation.

By the term functionalization, it is intended 30 to mean the application of a reagent to a solid surface that will permit molecule coating. By the

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accompanying drawings, showing by way of illustration a preferred embodiment thereof, and wherein:

- 1 illustrates а schematic Fig. electrodeposition set-up in accordance with preferred embodiment of the present invention;
- Fig. 2 is a schematic reaction chamber for glicidoxy-propyltriethoxy silane (GPTS) modification for passive deposition;
- illustrates schematic a electrodeposition set-up used for diazonium 10 functionnalization of silicon and stainless surfaces for passive deposition;
 - Fig. 4 shows the effect of duration of passive 32P-oligonucleotide on of deposition
- bromobenzenediazonium coated stainless steel surface; 15
 - Fig. 5 is a line graph of electrodeposition of 15-mer oligonucleotide on gold electrode as a function of potential;
- Fig. 6 illustrates the adsorption isotherm of 15-mer oligonucleotide on gold electrode at different 20 pH of the electrolyte solutions;
 - Fig. 7 illustrates the adsorption isotherm of 8-mer oligonucleotide at different concentrations on gold electrode;
- Fig. 8 illustrates the effect of duration of 25 polarization on the level of coating of radioactive 15-mer oligonucleotide onto gold plated stent;
 - Fig. 9 illustrates the effect of increasing activity of radioactive 15-mer oligonucleotide on coating onto gold plated stent;

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Fig. 10 illustrates the effect of duration of polarization on the level of coating of radioactive 15-mer oligonucleotide onto stainless steel stent;

Fig. 11 illustrates the effect of increasing 5 activity of radioactive 15-mer oligonucleotide on coating onto stainless steel stent;

Fig. 12 is a scan graph of gold plated stents coated with the electrochemical method of the present invention illustrating the distribution of the radioactive molecules onto the metallic surface along the length of the stent;

Fig. 13 is a scan graph of stainless steel stents coated with the electrochemical method of the present invention illustrating the distribution of the radioactive molecules onto the metallic surface along the length of the stent;

Fig. 14 is a line graph of the *in vitro* retention profile of ³²P-oligonucleotide coated onto the surface of a gold plated stent;

Fig. 15 is a line graph of the *in vitro* retention profile of ³²P-oligonucleotide coated onto the surface of a stainless steel stent;

Fig. 16 is a line graph of the retention profile of ³²P-oligonucleotide-coated gold stent (16 mm) when implanted in porcine coronary; and

Fig. 17 is a line graph of the retention profile of ³²P-oligonucleotide-stainless steel stent (18 mm) when implanted in porcine coronary artery.

30 DETAILED DESCRIPTION OF THE INVENTION

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In accordance with the present invention, there is provided a method for electrodepositing a radioactive molecule on a device for preventing restenosis.

In a preferred embodiment of the invention, the deposition is an electrodeposition as illustrated in Fig. 1 with the potentiostat/Galvanostat (EG&G model 273A) 20, hereinafter referred to as the potentiostat. In fact, Fig. 1 illustrates the Schematic drawing of the electrochemical cell and angioplastic device used for radioactive molecule coating onto gold and stainless steel surfaces.

embodiment, electrodeposition In this effected under a nitrogen atmosphere (N_2) , in a glass The stent 24, which acts as the working cell 22. electrode, is submerged in the electrolyte 26 with a reference electrode 28 (preferably a PdH₂ electrode) and a counter electrode 30 (Pt plate). The three electrodes are connected to the potentiostat 20, which is itself connected to a computer 32 for recording the The cell 22 is provided with a working conditions. cover 34 provided with holes for allowing the wires of the electrodes to pass through. The cover 34 is also provided with a gas inlet 36 and a gas outlet 38 for allowing nitrogen to be circulated.

In another preferred embodiment of the invention, the deposition is a passive deposition in which case the set up is similar to the one illustrated in Fig. 1, with the exception that no potentiostat 20 is needed. In such an embodiment, the alternate method of depositing a radioactive

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In another preferred embodiment of the invention, the deposition is a passive deposition in which case the set up is similar to the one illustrated in Fig. 1, with the exception that no potentiostat 20 is needed. In such an embodiment, the alternate method of depositing a radioactive

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polyanionic radioactive complex, such as а oligonucleotide, comprises the step of modifying the oligonucleotide by adding a thiol-containing group. The thiol-containing group may be for example a C_6 chain carrying a thiol function at its extremity and which is added at the 5' end of the oligonucleotide. The so-modified oligonucleotide may be labeled with 32P or other radioactive elements. A gold or gold-coated stent is incubated in either 0.1M potassium phosphate tetrahydrofuran buffer (KH₂PO₄ рΗ 7.0)or pure containing the radiolabeled oligonucleotide. After a 60 minute incubation period at room temperature, the stent is rinsed with distilled water. The radioactive oligonucleotide attaches to gold by the thiol group, radioactively coated stent. producing a This preferred embodiment is only an example (refer to example I) of passive deposition caused by the high affinity of gold for thiol group.

Another example of passive deposition is based 20 on the surface coating with silicon (Si) or silicon oxyde (SiO₂₎ followed by surface functionnalization with substrates. In this other preferred embodiment of SiO₂-treated invention, the surface is modified with glicidoxy-propyltriethoxy silane (GPTS), whereas the Si-treated surface is functionnalized with 25 4-bromobenzenediazonium tetrafluoroborate (diazonium). Stainless steel surface can be directly activated with 4-bromobenzenediazonium tetrafluoroborate without Si/SiO2 pre-treatment. The GPTS modification 30 passive (Fig. 2), whereas the diazonium deposition is an electrochemical functionalization, in which case

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the set up is similar to the one illustrated in Fig. 3.

Fig. 2 illustrates a Schematic drawing of the reaction chamber for glicidoxy-propyltriethoxy silane (GPTS) modification of silicon oxyde treated surfaces.

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In Fig. 2, the substrates are taken out of the oven they are placed in the various slots of the 2 glass holders 50. Each holder is hooked to the reaction chamber 52 were the silanization will take The whole lot is then placed inside a glove place. box which is under dry N_2 atmosphere. Once inside the glove box the GPTS reaction compounds were then added, in sequence, to the reaction chamber. A magnetic stirring bar 54 is added to the reaction mixture, the reaction chamber is then closed and removed from the The reaction chamber is connected to a glove box. with water circulator 56 temperature control. Stirring is initiated and the reaction is allowed to proceed for 4 hours at 70°C, under continuous N₂ flow 58 originating from a gas tank.

Fig. 3 illustrates Schematic drawing of the electrochemical cell used for bromobenzenediazonium functionnalization of silicon and stainless steel surfaces.

In Fig. 3, the electrochemical cell 22 was a standard three-electrode setup. The reference electrode 28 used was a saturated Calomel electrode (SCE) and the counter electrode 30 was platinum foil (1 cm²). The bromo-aryldiazonium solution was used as the electrolyte for cyclic voltammetry in order to attach the bromo-aryldiazonium to the surface (0.5 cm²

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area) of the Si or 316L substrates acting as working electrode 24. A scanning potentiostat was used to apply dc potentials to the working electrodes. The current-voltage response was recorded on an XY recorder.

In this preferred embodiment of the invention, the alternate method of depositing a radioactive such а radioactive polyanionic complex, as oligonucleotide, comprises the step of modifying the oligonucleotide by adding an amine-containing group. The amine-containing group may be for example a C6 chain carrying an amine function at its extremity and which is added at the 5' end of the oligonucleotide. The so-modified oligonucleotide may be labeled with 32P or other radioactive elements.

This preferred embodiment is only an example of passive deposition caused by the high affinity of GPTS and diazonium substrates for amine group.

In another embodiment of the invention, the 20 radioisotope can be attached to other radioisotopecarrying molecule.

For instance, in the preferred embodiment of an electrodeposition set-up (Fig. 1) where the stent plays the role of the anode (positively charged), a negatively charged molecule can be used effective electrodeposition onto the stent surface. Preferred negatively charged molecules can be for example without limitation labeled DNA or RNA, labeled analogs thereof, labeled nucleotides, labeled diethylene radioactive H_3PO_4 , triamine

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pentaacetic acid (DTPA) or labeled polyanionic complexes.

preferred In another embodiment of an electrodeposition set-up where the stent plays the role of the cathode (negatively charged), a positively be used for effective charged molecule can an electrodeposition onto the stent surface. Such positively charged molecule can be for example without limitation labeled conjugated polypeptides, labeled cationic peptides, labeled dextran, labeled chitosan or labeled polyamines.

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accordance with one embodiment In of invention, there is provided a process that can be performed in a daily practice moments prior to the 15 implantation of the device in a catheterization laboratory or in the radiation oncology department, and administered to the patient according to specification desired. The vehicle carrying the radioisotopic source such as a beta-source (32P) preferably short DNA 20 a sequence (15 mer oligonucleotides linked together by 11 phosphorothioate bounds), rendering the long time. Strong binding of DNAstable over a oligonucleotides was reported on gold (Sellergren et al., Anal. Chem., 68(2):402-407, 1996). 25

When double-stranded nucleic acid is used to be coated on the stent, a first non-radiolabeled strand of this double-stranded nucleic acid can be coated on the stent in accordance with one embodiment of the invention. The second complementary strand of the double-stranded nucleic acid can be labeled and

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annealed to the first strand. Such embodiment is also envisioned by the present invention, and is also encompassed in the term a radioactively coated device.

While a β -emitter source of radioisotope is preferred, other sources of radioisotope can also be used in accordance with the present invention.

The radioisotopic source is determined according to the treatment determined. Depending on the cases, the radiotherapy might vary from one patient to another. Accordingly, the radioisotopic source will be determined based on the half-life of the radioisotopic source, its energy and the specific activity of the radioisotopic source desired. The determination of the radioisotopic source is within the skill of a person of the art.

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Preferably the radioactive molecule comprises a β emitter. Preferred β -emitters are selected from the group consisting of Antimony-124, Cesium-134, Cesium-137, Calcium-45, Calcium-47, Cerium 141, Chlorine-36, Cobalt-60, Europium-152, Gold-198, Hafnium-181, 20 Holmiun-166, Iodine-131, Iridium-192, Iron-59, Lutetium-177, Mercury-203, Neodymium-147, Nickel-63, Phosphorus-32, Phosphorus-33, Rhenium-186, Rhodium-Rubidium-86, Ruthenium-106, Samarium-153, 106, Scandium-46, Silver-110m, Strontium-89, Strontium-90, 25 Sulfur-35, Technetium-99, Terbium-160, Thulium-170, Tungsten-188, Yttrium-90 and Xenon-133.

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Electrodeposition

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Stainless steel stent characteristics and surface pretreatment

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In a preferred embodiment, ACS multi-link RX DUETTM stents (Guidant Vascular Intervention, Santa Clara, CA) of 13 to 23 mm of length were used in accordance with the present invention. Commercial 316L stainless steel samples, in the form of 1 cm diameter discs, 0.2 mm thick (Goodfellow Cambridge Ltd., Huntingdon, England) were also used.

Deposition or electrodeposition is more effective when the surface to be coated is cleaned to remove contaminants. To do so, stents to be coated were first washed with organic solvents (acetone or methanol) for removing contaminants and then airdried. Another example of surface cleaning is argonion sputtering. The sputtering of stents or discs was carried out under the following conditions:

Initial chamber pressure 1,3x10-8 torr

Pressure after argon introduction 1,3x10-5 torr

Energy 2 keV

Focus voltage 1 keV

Current 4 μ A

Time 20 min (discs)

5 min (stents)

Again, transfer of discs and stents was carried out under vacuum.

An electrochemical method can also be used for cleaning stainless steel surface (stents or discs). Electropolishing was carried out in the glove box using a voltage generator. The cleaning solution was composed of 1 M oxalic acid 15% hydrogen peroxide.

Only two electrodes were used: the sample was one and the other, a Pt disk. A potential of 10 V was applied for 10 minutes between these electrodes, followed by extensive rinsing and transferred to the electrochemical deposition cell of Fig. 1.

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Gold stent characteristics and surface pre-treatment

In a preferred embodiment, NIROYAL™ 24 ct gold plated stents (Boston Scientific Ireland Ltd. Ballybrit Business Park, Galway, Ireland) of 13 to 23 mm of length were used in accordance with the present invention. Gold-coated 316L discs in the form of 1 cm diameter discs (Goodfellow) were also used.

Gold surface can be directly used for electrodeposition or cleaned with argon-ion sputtering in conditions as previously described for stainless steel metal.

³²P-oligonucleotide compounds

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In one embodiment of the invention, the vehicle chosen for carrying the beta-source (32P) is a short DNA sequence (15 mer oligonucleotides linked together by 11 phosphorothicate bounds, patent No. 5,821,354). This short DNA sequence was reported to be highly stable and effective in the prevention of cell proliferation with no side effects (Fareh et al., Circulation, 99:1477-1484, 1999).

For the embodiment of passive deposition, the radioactive molecule has at its 5' end either an amine-containing group as for example a C_6 chain carrying an amine function or a C_6 chain carrying a thiol function. The amine- and thiol-modified

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oligonucleotides may be labeled with ³²P or other radioactive elements.

Electrodeposition of 32P-oligonucleotides

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Electrodeposition is effected in an 32 P electrochemical cell containing the oligonucleotides (75 μ Ci/50 μ L of water) diluted in 250 μL of acetate sodium buffer, (CH₃CH₂CO₂Na.3H₂O at 0.2 M) at pH 8.5. In the electrochemical cell containing both 32P-oligonucleotide electrolyte and solutions, metallic stent was fixed to the anode and the cathode was composed of a platinum wire of 2 mm diameter and 5 cm length or a Pt plate.

Electrodeposition is performed by applying a voltage of 1 Volt (50-60 mA) for 15 minutes using a standard potentiostat 20 at room temperature.

Electrodeposition succeeds in binding 2.5% of initial ³²P-oligonucleotides on the stent surface, when any post-treatments were applied.

Another example of electrolytes for effective 20 electrodeposition is aqueous phosphate solutions.

To evaluate the electrodeposition of the 15-mer oligonucleotide onto the gold surface (electrodes and plated stents) in aqueous phosphate solutions as electrolytes, a method for studying the adsorption of DNA was used. Briefly, cyclic voltammetry (CV) coupled to electrochemical quartz crystal nanobalance system was used to study the adsorption of organic molecules on gold surface. Since the frequency variation of the crystal and the cyclic voltammogram are recorded simultaneously, this method allows to measure the quantity of molecules adsorbed on gold in the whole

potential window and in only one cycle. Fig. 5 illustrates a surface concentration (τ) of 15-mer oligonucleotide (3.8 μM) on gold electrodes as a function of potential in the pH=6.98-7.0 phosphate buffered solution. The scan rate is 100 mV/s. An arrow indicates the beginning of the scan.

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As illustrated in Fig. 5, the electrosorption of 15-mers increases as the polarization potential is increased and reaches a maximum E = 1.1-1.2 V vs. SCE reference electrode) (see Fig. 5): At (calomel surface 1.1-1.2 V, the potential higher than concentration of the molecule starts to decrease. This phenomenon can be explained by the oxidation of gold occurring at these potentials when using phosphate buffer as electrolyte solution.

After repeating the same procedure for several concentrations of 15-mer molecule, different adsorption isotherm at constant potential was obtained in those conditions. For that example, gold plated stents (NIROYAL) and commercial electrodes of gold (0.1684 cm², Aldrich Canada) were used. Gold wires were inserted in a Kel-F rod in order to have only one tip of the wire in contact with the solution. Kel-F was chosen as the support material because it is inert in The electrode was acidic and basic aqueous media. polished with a 0.5 µm alumina suspension. Aqueous phosphate solutions were prepared from a Na₂HPO₄.7H₂O (17.8897 g/L) and a KH_2PO_4 (9.0725 g/L) solutions.

Fig. 6 illustrates the adsorption isotherm of 30 15-mer oligonucleotide on gold electrodes at E=1.1 V, SCE (calomel reference electrode) in phosphate

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at pH=6.98-7.0, pH=8.04buffered solutions In Fig. 6, the adsorption isotherm of nonpH=5.59. radioactive 15-mer oligonucleotide on gold at 1.1 V vs. SCE is presented for the three buffered solutions One may note that at pH=6.98-7.0, studied. increase of the concentration of oligonucleotide leads to an increase of the surface concentration, until a plateau is attained at a concentration of about 20 μM . Beyond this point, an increase in the concentration of 15-mer oligonucleotide does not enhance the surface Similar experiments were performed at concentration. pH=5.59 and pH=8.04 showing that electrosorption of 15-mer oligonucleotide on gold is more effective at pH=6.98-7.0. Higher electrosorption was obtained when polarization was performed at 60°C.

Fig. 7 illustrates the adsorption isotherm of 8-mer oligonucleotide on gold electrodes at E=1.1 V, (calomel reference electrode) phosphate in SCE buffered solutions at pH=6.98-7.0. As shown in Fig. 8-mer oligonucleotides electrosorption of 20 effective onto gold electrode surface, when applying a V during 15 minutes at of 1.2 voltage temperature. Higher electrosorption was obtained when polarization was performed at 60°C. Similar adsorption isotherm of a 35-mer oligonucleotide was reported. 25

When gold stents (16 mm) were polarized at 1.2 V during 15 to 30 minutes in presence of ^{32}P -oligonucleotide (800 μ Ci) at room temperature, 2.5 to 3 μ Ci of radioactivity were detected onto the stent surface (corresponding to 0.3% of efficacy coating)

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and no alteration of the surface integrity was reported.

Other electrolyte useful for the present invention

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³²P-oligonucleotide depositions were carried out in 0,1 M HClO₄ under nitrogen (bubbler), at a potential of 1,45 V vs. SCE (saturated calomel electrode) and at a temperature of 60 ± 10 °C. For that preferred embodiment, higher coating was obtained at 60°C. However, coating of ³²P-oligonucleotide onto stainless steel or gold surfaces is also feasible and effective at room temperature.

The electrochemical cell (Fig. 1) was composed of three electrodes: i) the working electrode (our sample); ii) the counter electrode (Pt disk); and the reference electrode (Pd/PdH $_2$), calibrated before each measurement.

The reference electrode is made by flowing hydrogen on a Pd disk in 0,1 M $HClO_4$ for 30 minutes.

The effects of polarization duration and the initial activity were assessed with native gold stents of 16 mm, where no surface cleaning was performed. Similarly, stainless steel stent of 18 mm, previously cleaned with 1M oxalic acid 15% hydrogen peroxide were also used. A series of time of electrodeposition (5, 15, 30 and 60 min) were used.

Fig. 8 illustrates the effect of coating duration on electrodeposition level (16 mm-gold plated stents). As illustrated on Fig. 8, the maximal coating was reached at 5 to 15 min on gold surface, underlying the rapid and effective electrodeposition of ³²P-oligonucleotide onto the gold stent (average of

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1.6%). Fig. 9 reports the activity-dependent coating onto gold surface when increasing activity of 32Poligonucleotide (0.25, 0.5, 1 and 2 mCi) were tested during 5 minutes. However, higher effective coating was obtained at low initial activity (1.9%, 1.2%, 0.8% 0.250, 0.500, 1.0 2.0 0.5% for and and respectively). In those conditions (5 min of coating), an effective coating of 0.5% (average) was obtained, corresponding, for example, of an activity of 10 µCi onto a 16 mm-gold stent. Similar levels were obtained when the gold surface was cleaned with argon-ion sputtering.

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Fig. 10 ilustrates the effect of coating duration electrodeposition level (18 mm-stainless steel stents). As illustrated in Fig. 10, a similar coating 15 of 0.5% was obtained at 5 to 15-20 min to reach a maximal coating (1.0%) at 60 min on stainless steel surface. underlying the rapid and effective of ³²P-oligonucleotide electrodeposition onto stainless steel stent. When increasing activity of 32P-20 oligonucleotide (0.25, 0.5, 1 and 2 mCi) were tested, similar coating with activity of 0.25 to 1.0 mCi (average of 2.5-3.0 μ Ci) were obtained, whereas higher activity (2.0 mCi) led to significant amount of 32Poligonucleotide onto the stainless steel stent surface 25 (Fig. 11). In those conditions (15 min of coating), an effective coating of 0.5% (average) was obtained, corresponding, for example, of an activity of 10 μ Ci mm-stainless steel stent. illustrates the effect of increasing activity of 32P-30 oligonucleotide on coating efficiency (18 mm-stainless

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steel stents). Similar levels were obtained when the stainless steel surface was cleaned with argon-ion sputtering.

32P-oligonucleotide distribution onto the surface

5 Coated stents (n=6 gold plated and n=6 stainless steel stents), using HClO₄ as electrolytes, were scanned for 4 hours to visualize the distribution of ³²P-oligonucleotides onto the metallic surface along the length of the stent. The stent radiation uniformity was measured using a 0.5 mm slit in front of a Geiger counter which was moved over the stent in 0.5 mm steps by a computer-controlled stepping motor.

Regarding the scan graph of the coated stent, the electrodeposition was highly uniform on the metallic surface of gold plated (Fig. 9) and stainless steel stents (Figs. 12 and 13). Figs 12 and 13 illustrate scan graphs of a gold plated stent or of a stainless steel stent, respectively, coated with ³²P-oligonucleotide.

Similar uniform distribution of radioactivity was also obtained when acetate sodium buffer as electrolytes was used to perform electrodeposition in the set-up of Fig. 1.

Post-treatment of the radioactive stents (in vitro 25 retention)

Following electrodeposition in the acetate sodium buffer electrolyte, radioactive stents in distilled water for rinsed 24 hours at room temperature and air-dried or sonicated for 30 minutes. Biological treatments were investigated by incubating radioactive stents with DMEM supplemented with an enzyme solution consisting of 5 μ l of Nuclease S₁

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 $(332 \text{ U}/\mu\text{l})$, 1 μl of Exonuclease III (E. 100 U/ μ l), and 1 μ l of phosphodiesterase (0.5 U/ μ l) in presence of 10% Fetal Bovine Serum (FBS, overnight at 37°C. Following incubation of coated stents in water for 24 hours, 80% of initial coating solution remained on the metallic surface, whereas additional sonication procedure (30 minutes) reduced to 50% the retention rate. Following a biological treatment (blood mimicking enzyme solution) of coated stents at 37°C during 14 to 16 hours, 12% of the amount of radioactivity remained on the stent, when compared to the initial electrodeposition level.

Following electrodeposition in the HClO₄ 0.1M electrolyte, radioactive coated stents (n=8)gold 15 plated stents of 16 mm) were incubated in biological medium composed of DMEM in presence of 20% Fetal Bovine Serum (FBS, Gibco) at 37°C with constant Those physical and biological conditions agitation. were used to mimic in vivo conditions. A sample of medium (50 μ L) was counted following 15, 30, 60, 120, 20 240 min 24 and hours of incubation. Fig. illustrates the retention profile of coated oligonucleotide onto 16 mm-gold plated stent surface in in vitro conditions (blood mimicking conditions). 25 As illustrated in Fig. 14, following incubation of gold coated stents at 37°C, a progressive elution of the 32P-oligonucleotide was reported, corresponding to a remaining activity of an average of 50, 40 and 35% after 60, 120 and 240 min respectively. A significant 30 sustained activity of 10-12% is reported up to 8 days treatment in blood mimicking conditions, when

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compared to the initial electrodeposition level (Fig. 14).

Similarly, radioactive coated stents stainless steel stents of 18 mm) were incubated in biological medium composed of DMEM in presence of 20% Fetal Bovine Serum (FBS, Gibco) at 37°C with constant agitation. A sample of medium (50 µL) was counted following 15, 30, 60, 120, 240 min and 18 hours of incubation. Fig. 15 illustrates the retention profile 10 of coated 32P-oligonucleotide onto 18 mm-stainless steel stent surface in in vitro conditions (blood mimicking conditions). As illustrated in Fig. following incubation of stainless steel coated stents 37°C. at a progressive elution of the oligonucleotide was 15 reported, corresponding remaining activity of an average of 45 to 37-40% after 60 to 240 min. A significant sustained activity of 40% is reported following 1 day of treatment in blood mimicking conditions; an average of less than 10% of initial electrodeposition level remained up to 7 days 20 of incubation.

Regarding the combination of a simple method to produce radioactive stent and a well defined release of the radioactive molecule from the angioplastic device, a classical stent-based radiation as well as a stent-based pharmacological approach can be envisaged to prevent restenosis.

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To reinforce the strength of the proposed radioactive coating, the metallic surface can be embedded in a simple manner. A series of biostable coatings and agar solution of 1 to 2% were tested and

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shown to improve the molecule retention by reducing the elimination of the ³²P-oligonucleotide from the metallic surface. Polymer coating (such as parylene) already used for medical application is proposed to embed the angioplastic device.

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To support the pharmacological approach, the well-defined elution from the coated stents can serve as a local drug delivery device to prevent restenosis, based on data obtained on intra-arterial sustained-release of beta particles. In that case no device embedding is performed.

Mechanical properties of the radioactive coated stents

General observations were done on the coated stents such as determination of color and rigidity. 15 Mechanical properties were estimated by mimicking in vivo stent deployment. After mounting the stent on deflated balloon, the balloon was inflated to 10-14 and the capability of stent deployment evaluated. physical alteration No (color 20 deployment ability, surface deterioration, cracking and flaking of the surface) was observed in coated stents according to the present invention. fluoroscopy, the visibility of the coated stent was not modified.

25 Implantation of the radioactive coated stent in porcine coronary arteries

Domestic pigs were sedated with intramuscular injection of ketamin, azaperon and atropine to undergo anesthesia with thiopental sodium (iv). The pigs were intubated and ventilated with a mix of isoflurane 2% and oxygen during the procedure. An 8 Fr. guiding catheter was advanced through a femoral sheath with a

0.035 J quide-wire, under fluoroscopic monitoring in the ascending aorta. The guide wire was then removed, allowing the guiding catheter to be positioned in the ostium of the target vessel. Prior to performing the angiography, a bolus of 1 ml of nitroglycerin solution with a concentration of 0.3 mg/mL is injected intracoronary. The angiography was then performed in at least two near orthogonal views that visualize the target site of right coronary artery (RCA) or left circumflex artery (LCX) of the pig. A quantitative coronary angiography (QCA) measure was done to assess the vessel size for adequate stent implantation. Stent was advanced to the target site and balloon inflation at 10 to 12 atm for 30 seconds was performed to adequately deploy the stent (2 stents per pig). Following stent implantation, the balloon was deflated and the catheter withdrawn. Control angiography was then performed to document any residual luminal stenosis or vessel wall dissection. Ιf spasm was documented, 1 ml of nitroglycerin solution at a concentration of 0.3 mg/mL was injected coronary.

Macroscopical observations

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After stent implantation, treated pigs were 25 maintained for 6 hours under observation. Following pig euthanasia with a lethal dose of KCl, myocardium dissected to remove stented arteries. macroscopical observation of the heart and stented artery was performed to explore the potential side 30 effects of coating stent implantation (thrombogenicity, clotting, etc.). Stents were then removed from the artery to be counted to assess the in vivo retention of $^{32}\text{P-oligonucleotides}$ onto the stent surface. For that example, coated-stents generated with acetate sodium buffer as electrolytes and Fig. 1 as electrochemical set-up were used for coronary implantation

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fluoroscopy ' and macroscopical Following effects side related to the observations, no implantation of a radioactive treated stent according to the present invention were observed either in the in the implanted artery. myocardial tissue orMeasurements of radioactivity level of coated stents revealed that 6 hours following stent implantation 45% initial coated activity remained on the stent surface, whereas low radioactivity was detected in the target artery (less than 3%), suggesting that coronary wash-out eliminates more than 44% of the drug from the stent surface within 6 hours. The biological half-life of coated 32P-oligonucleotides on the surface stent in coronary arteries was estimated porcine approximately 5.5 to 6 hours. The residence time of the coated 32P-oligonucleotides is 11to intra-mural administration of higher than direct liquid 32P-oligonucleotides using the Infiltrator® catheter (0.51 hours).

In vivo follow-up of 32P-oligonucleotide elution from coated stents

The catheter-based radiation detection *via* the endovascular detector permits the fine and continuous determination of the elution profile of the radioactive molecule from the stent. For that issue, gold-plated (16 mm) and stainless steel (18 mm) stents

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were used. ^{32}P -coated stents, generated with HCLO₄ as electrolytes, were implanted in porcine coronary arteries (LCX and RCA) for 3 hours as previously described.

5 Using the endovascular detector, measurements of radioactivity levels were done every 30 seconds to local ³²P-oligonucleotide elution from follow stent. the endovascular Αt end οf continuous monitoring (up to 3 hours), the pig was sacrificed with a lethal dose of KCl, myocardium was dissected to 10 remove stented arteries. Blood was collected during the experiment.

Figs. 16 and 17 illustrate the retention profile of coated ³²P-oligonucleotide gold-plated stent (16 mm) and coated ³²P-oligonucleotide stainless steel stent (18 mm), respectively, when implanted in porcine coronary artery. As illustrated in Figs. 16 and 17, the elution profile of gold-plated and stainless steel stents, electrocoated with ³²P-oligonucleotide, is characterized by two components: a rapid elution during the first 30 min. and a significant sustained radioactivity, which is maintained up to 3 hours. Few radioactivity was detected in blood samples, stented coronary and the adjacent myocardium.

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The present invention will be more readily understood by referring to the following examples, which are given to illustrate the invention rather than to limit its scope.

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EXAMPLE I

Passive Deposition Using Thiol-modified Oligonucleotide

Coating of gold-plated stents with ³²P-oligonucleotide containing a 5'-end thiol moiety

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NIROYAL gold-stents (6 mm) were placed piranha solution (3:7 v/v, 30% H_2O_2 : 98% H_2SO_4) at 70°C for 20 min. Stents were then washed with H_2O , acetone, ethanol and H₂O and dried under a stream of N₂ gas. The pre-cleaned stents were then placed either in potassium phosphate buffer (K2HPO4 - KH2PO4; pH 7.0) or in tetrahydrofuran (THF) containing 100 µCi of 32Poligonucleotide containing a 5'-end thiol moiety to be incubated 60 min. at room temperature. Radioactive stents were then rinsed 3 times with 50 ml of H2O.

Radioactivity levels of NIROYAL gold stents 1.15 µCi following passive deposition was when incubated in pure tetrahydrofuran and 0.02 µCi when incubated in potassium phosphate buffer, corresponding 20 to an efficiency of passive deposition of 1.15% and 0.02% respectively. Following immobilization, stents were incubated 2 days in pig blood at 37°C with constant agitation. Stents were then removed from biological conditions to be rinsed with water and 25 remaining radioactivity was assessed by scintillation counting. NIROYAL gold stents incubated in the tetrahydrofuran solution supplemented with oligonucleotide lost 33% (0.80 μ Ci residual activity) and 66% (0.34 μ Ci residual activity) of its initial 30 activity after 1 and 2 davs of incubation. respectively. Stents incubated in potassium phosphate

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buffer lost 100% of their initial activity after 1 day of incubation.

EXAMPLE II

5 <u>Passive Deposition Using GPTS Modification</u>

Functionalization of Si/SiO₂ substrates using glicidoxy-propyltriethoxy silane (GPTS)

- Substrates:

The Si/SiO2 substrates were 1 cm x 1 cm plates

10 taken from diced 4 inch wafers (Tronics Microsystems,
Grenoble). The Si (100) is n-type, phosphorous doped
to a density of 10¹⁵ cm⁻³, and has a thickness of 0.3

µm. The Si is covered with a thermally grown SiO₂ layer
which is 150 Å thick. The back of the Si plates was

15 covered with a Cr/Au ohmic contact.

- Cleaning:

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The substrates were placed in boiling acetone (Sprectrograde, Aldrich) for 5 minutes, followed by another 5 minutes in boiling methanol (Sprectrograde, Aldrich). The substrates were then dipped in sulfochromic acid (prepared by adding 95 mL of concentrated sulfuric acid (H2SO4) to 5 \mathfrak{mL} saturated aqueous solution of potassium dichromate $(K_2Cr_2O_7)$) for 4 minutes at room temperature.

The substrates were rinsed for 15 seconds with distilled-deionized (d-d) water, and then placed in boiling d-d water for 10 minutes. Following this, the substrates were dried with N_2 flow and placed in a clean oven (ambiant atmosphere) at 140°C for 1 hour.

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- GPTS modification:

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substrates, with the reaction chamber The illustrated in Fig. 2, are placed inside a glove box which is under dry N_2 atmosphere. Once inside the glove box, the substrates were placed in the reaction chamber and the GPTS reaction compounds were then added, in sequence, to the reaction chamber. reaction mixture consisted of 111 mL of o-xylene (98% sealed under nitrogen, Aldrich), followed by 12.5 mL of GPTS (98% purity, Fluka), and then 1.5 mL of diisopropyl-ethyl amine (99.5% purity sealed under nitrogen, Aldrich) (for a batch of 8 substrates). A magnetic stirring bar is added to the reaction mixture, the reaction chamber is then closed and removed from the glove box.

The reaction chamber is connected to a water circulator with temperature control. Stirring is initiated and the reaction is allowed to proceed for 4 hours at 70° C, under continuous N_2 flow.

The substrates are removed from the reaction chamber, dipped in ethanol (Spectrograde, Aldrich) for 5 minutes (at room temperature), and allowed to dry under ambiant atmosphere. The substrates are finally stored individually in glass vials containing 5 mL of ethyl ether (99.9% purity HPLC grade, Aldrich).

consisting of a radioactive DNA or an analog thereof, a radioactive RNA, a radioactive nucleotide, a radioactive oligonucleotide, radioactive $\rm H_2PO_4$, radioactive diethylenetriaminepentaacetic acid, and a radioactive polyanionic complex.

- 25. The method of claim 24, wherein the radioactive molecule is a radioactive oligonucleotide.
- 26. The method of claim 25, wherein the oligonucleotide is a 8- to 35-mer oligonucleotide.
- 27. The method of claim 25, wherein the oligonucleotide is a 8- to 20-mer oligonucleotide.
- 28. The method of claim 25, wherein the oligonucleotide is a 15-mer oligonucleotide.
- 29. The method of claim 20, wherein the electric potential difference is negative.
- 30. The method of claim 29, wherein the radioactive molecule is selected from the consisting of radioactive conjugated polypeptides, radioactive cationic peptides, radioactive dextran, radioactive polyamines and radioactive chitosan.
- 31. The method of claim 20, wherein the angioplastic device is a stent.

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Immobilization of ³²P-oligonucleotide onto GPTS modified Si/SiO₂ substrates

 32 P-oligonucleotide (40 μ Ci, with or without a C₆ amino linker at the 5' end) is directly deposited onto the surface of a GPTS modified substrate. The 32 P-oligonucleotide solution was left to react for 2 hours on the GPTS surface in 0.01M in KOH, under humid atmosphere. The substrate surface was then rinsed with d-d water.

10 Results

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When passive deposition was performed Si/SiO₂ substrates functionnalized with GPTS, a 5-fold increase of coating was obtained with ³²P-oligonucleotide with amino linker, when compared to simple 32P-oligonucleotide (0.10% vs 0.02% of initial 15 activity, respectively), corresponding to a better affinity of 32P-oligonucleotide with amino linker to the GPTS surface than the non-modified oligonucleotide. Moreover, the radioactivity level due to immobilized 32P-oligonucleotide with amino linker 20 ³²P-oligonucleotide with initial increases concentration up to 300 µCi, at which point it appears to level off. Immobilization efficiency was better at a reaction temperature of 52°C (2.19% of 25 activity), when compared to 22°C (0.16% of initial activity), 37°C (0.19% of initial activity) and 70°C (1.0% of initial activity). A 12 to 13 fold-increase of coating was reported when deposition was performed at 52°C, when compared to room temperature conditions.

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EXAMPLE III

Passive Deposition Using Diazonium Modification

Electrochemical functionalization of Si and stainless steel substrates (discs and stents) with bromobenzenediazonium, and ³²P oligonucleotide immobilization

The procedure used to electrochemically modify the Si and the 316L Stainless Steel substrates is described in C. Henry de Villeneuve et al., (*J. Phys. Chem. B*, **101**, 2415-2419 (1997)).

Purity of chemicals and solvents

Chemicals	Source	Purity/Concentration
Trichloroethylene	Fisher Scientific	Reagent Grade
Ammonium Fluoride	J. T. Baker Chem.	40% Solution
	Co.	
Methanol	EM Scientific	HPLC Grade
Acetone	Fisher Scientific	HPLC Grade
Hydrofluoric Acid	Fisher Scientific	49%
4-Bromobenzene-	Aldrich Chem. Co.	96%
diazonium		
Tetrafluoroborate		
Sulfuric Acid	Mallinckrodt	96%

Substrates:

The silicon (Si, 100) substrates were 1x1 cm², taken from a diced wafer purchased from Tronics Microsystems (Grenoble, France). The Si was phosphorous doped (n-type) to a density of 10¹⁵cm⁻³. A gold/chromium film was deposited under vacuum at the backside of the Si substrate providing an ohmic contact. The stainless steel substrates were 316L type

(Fe/Cr18/Ni10/Mo3), 10 mm in diameter and 0.2 mm thick, from Goodfellow Cambridge Ltd. (Huntingdon, England). In a preferred embodiment, ACS multi-link RX DUETTM stents (Guidant Vascular Intervention, Santa Clara, CA) of 18 mm of length were used in accordance with the present invention. Stents were cut to have a 9 mm of length for experiments.

Prior to the electrochemical functionalization, both types of substrates were submitted to cleaning/etching procedure. The Si substrates were 10 cleaned by immersing in trichloroethylene, acetone, and methanol for 1 minute each, respectively. were rinsed in distilled-deionized (d-d) water dried with N2 flow. The Si substrates were then 15 chemically etched for one minute in hydrofluoric acid and six minutes in buffered ammonium fluoride, rinsed once again and dried using N_2 . The 316L substrates (discs and stents) were immersed in 50 mL of aqua regia (concentrated $HCl:HNO_3$, 4:1 (v/v)) for 1 minute, rinsed with d-d water and dried with N2 flow. 20

Bromo-aryldiazonium salt solution

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A 20mM aqueous solution of 4-bromobenzenediazonium tetrafluoroborate in $0.1M\ H_2SO_4$ and 2% HF was prepared by dissolving 0.54g of 4-bromobenzenediazonium tetrafluoroborate, 0.56 mL of concentrated H_2SO_4 and 4mL of concentrated HF in 100 mL of d-d water. The solution was deaerated by bubbling N_2 for approximately 20 minutes.

Electrochemical functionalization:

The electrochemical cell was a standard threeelectrode setup. The reference electrode used was a

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saturated Calomel electrode (SCE) purchased from Fisher Scientific and the counter electrode was platinum foil (1 cm^2) . The electrochemical cell is illustrated in Fig. 3.

The bromo-aryldiazonium solution was used as the electrolyte for cyclic voltammetry in order to attach the bromo-aryldiazonium to the surface of the Si or 316L substrates acting as working electrode. A scanning potentiostat (EG&G Princeton Applied Research Model 362) was used to apply dc potentials to the working electrodes. The current-voltage response was recorded on an XY recorder (Phillips, Model PM 8143).

A single-cycle voltammogram was run on each substrate. The current range was set at 1mA. The reductive scan was run from an initial potential of - 0.3 V to a final potential of - 1.9 V vs. SCE, and back. The scan rate was set at 100 mV/s. A typical reductive wave (at ~ -1.5 V) was observed for modification of a Si substrate. The current density is greater for the 316L substrate because of its greater conductivity and the reduction wave is observed at ~ - 0.95 vs. SCE.

Results

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In that series of experiments, all stainless steel surface (discs and stents) were functionnalized with diazonium and then coated in presence of 50 μ L (50 μ Ci) of ³²P-oligonucleotide/amino linker solution. They were rinsed as previously described. ³²P-oligonucleotide with a C6 amino linker at the 5' end was used for that embodiment.

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Using the discs surface, immobilization efficiency reached a level of 9.5 μ Ci/cm² with initial activity of 50 µCi of 32P-oligonucleotide/amine linker solution (9.5% of efficiency). Increasing 5 activity to 300 μ Ci improved the coating efficiency to 15.8 $\mu \text{Ci/cm}^2$. Coating was better at a reaction temperature of 52°C, when compared to 22 and 70°C. A 2 to 3 fold-increase of coating was reported when deposition was performed at 52° C (8 to 18 μ Ci/cm²), 10 when compared to room temperature conditions. As shown in Fig. 4, the level of coating increased with the reaction time (5, 15, 30, 60 and 120 minutes). The radioactivity undergoes a gradual increase with reaction time, going from approximately 6 μCi/cm² at 5 minutes to 17.5 μ Ci/cm² at 120 minutes. When compared 15 to disk functionnalization, immobilization efficiency was increased by 1.4 fold on stainless steel stent surface. An average of 2.93 μCi of 32P-oligonucleotide/amino linker solution was coated on 20 a stainless steel stent of 9 mm, corresponding to a level of 24.5 μ Ci/ cm² or an activity of 5.9 μ Ci for a stent of 18 mm. Those experimental conditions underlined the rapidity of the coating 32P-oligonucleotide/amino linker solution of the stent surface. 25

Fig. 4 illustrates the effect of duration of passive deposition on ³²P-oligonucleotide coating onto bromobenzenediazonium-treated stainless steel surface.

While the invention has been described in 30 connection with specific embodiments thereof, it will

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be understood that it is capable of further modifications and this application is intended to cover any variations, uses, or adaptations of the invention following, in general, the principles of the invention and including such departures from the present disclosure as come within known or customary practice within the art to which the invention pertains and as may be applied to the essential features hereinbefore set forth, and as follows in the scope of the appended claims.

What is claimed is:

- 1. A method for depositing a charged molecule on an angioplastic device, said method comprising the step of contacting the angioplastic device with a solution containing the charged molecule under suitable conditions for deposition of the charged molecule on the angioplastic device.
- 2. The method of claim 1, wherein the deposition is a passive deposition.
- 3. The method of claim 2, wherein the angioplastic device has gold on its surface, and wherein the charged molecule comprises a thiol-containing group for attaching to the gold on the angioplastic device.
- 4. The method of claim 1, wherein the deposition is an electrodeposition.
- 5. A method for electrodepositing a charged molecule on an angioplastic device, said method comprising the step of applying an electric potential difference between said angioplastic device and a solution containing the charged molecule, said charged molecule having a charge opposite to the electric potential difference and being thereby electrodeposited on the angioplastic device.

- 6. The method of claim 5, wherein the electric potential difference is positive.
- 7. The method of claim 5, wherein the electric potential difference is negative.
- 8. The method of claim 7, wherein the radioactive molecule is selected from the group consisting of conjugated polypeptides, cationic peptides, dextran, polyamines and chitosan.
- 9. The method of claim 5, wherein the angioplastic device is a stent.
- 10. The method of claim 9, wherein the angioplastic device has a metallic surface.
- 11. The method of claim 10, wherein the metallic surface is selected from the group consisting of stainless steel, gold, tantalum, nickel and titanium or any alloy thereof.
- 12. The method of claim 5, further comprising before the step of applying an electric potential difference, a step of washing the angioplastic device with a solvent for removing impurities at the surface of said angioplastic device.
- 13. The method of claim 5, further comprising after the step of applying an electric potential difference, a step of rinsing the angioplastic device

for removing free molecules at the surface of said angioplastic device.

- 14. An angioplastic device for preventing restenosis in a coronary and/or peripheral artery, said device comprising a charged molecule deposited on its surface.
- 15. The angioplastic device of claim 14, wherein the angioplastic device is a stent or a microcatheter wire.
- 16. A method for depositing a radioactive charged molecule on an angioplastic device, said method comprising the step of contacting the angioplastic device with a solution containing the radioactive charged molecule under suitable conditions for deposition of the radioactive charged molecule on the angioplastic device.
- 17. The method of claim 16, wherein the deposition is a passive deposition.
- 18. The method of claim 17, wherein the angioplastic device has gold on its surface, and wherein the radioactive charged molecule comprises a thiol-containing group for attaching to the gold on the angioplastic device.
- 19. The method of claim 16, wherein the deposition is an electrodeposition.

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A method for electrodepositing a radioactive 20. charged molecule on an angioplastic device, said method comprising the step of applying an electric potential difference between said angioplastic device and a solution containing the radioactive charged molecule, said charged molecule having a charge opposite to the electric potential difference and being thereby electrodeposited on the angioplastic device.

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- The method of claim 20, wherein the electric 21. potential difference is positive.
- 22. The method of 20, wherein claim the radioactive molecule comprises a β -emitter.
- The method of claim 22, wherein the β -emitter is Antimony-124, Cesium-134, Cesium-137, Calcium-45, Chlorine-36, Calcium-47, Cerium 141, Cobalt-60, Europium-152, Gold-198, Hafnium-181, Holmiun-166, Iridium-192, Iodine-131, Iron-59, Lutetium-177, Mercury-203, Neodymium-147, Nickel-63, Phosphorus-32, Phosphorus-33, Rhenium-186, Rhodium-106, Rubidium-86, Ruthenium-106, Samarium-153, Scandium-46, Silver-110m, Strontium-89, Strontium-90, Sulfur-35, Technetium-99, Terbium-160, Thulium-170, Tungsten-188, Yttrium-90 and Xenon-133.
- 24. The method of claim 21, wherein the radioactive molecule is selected from the group

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- 32. The method of claim 31, wherein the angioplastic device has a metallic surface.
- 33. The method of claim 32, wherein the metallic surface is selected from the group consisting of stainless steel, gold, tantalum, nickel and titanium or any alloy thereof.
- 34. The method of claim 20, further comprising before the step of applying an electric potential difference, a step of washing the angioplastic device for removing impurities at the surface of said angioplastic device.
- 35. The method of claim 34, wherein the angioplastic device is cleaned with a solvent.
- 36. The method of claim 20, further comprising after the step of applying an electric potential difference, a step of cleaning the angioplastic device for removing free radioactive molecules at the surface of said angioplastic device.
- 37. An angioplastic device for preventing restenosis in a coronary and/or peripheral artery, said device comprising a radioactive charged molecule deposited on its surface.
- 38. The angioplastic device of claim 37, wherein the radioactive molecule comprises a β -emitter.

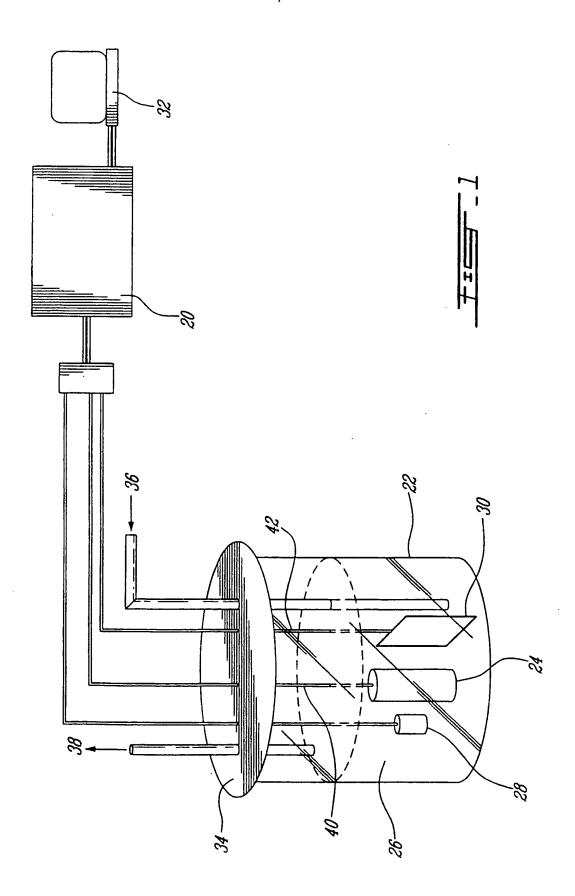
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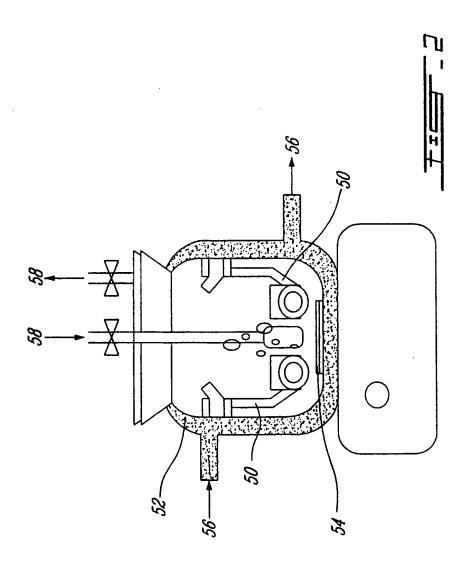
- The angioplastic device of claim 37, wherein the β -emitter is selected from the group consisting of Antimony-124, Cesium-134, Cesium-137, Calcium-45, Calcium-47, Cerium 141, Chlorine-36, Cobalt-60, Europium-152, Gold-198, Hafnium-181, Holmiun-166, Iridium-192, Iodine-131, Iron-59, Lutetium-177, Mercury-203, Neodymium-147, Nickel-63, Phosphorus-32, Phosphorus-33, Rhenium-186, Rhodium-106, Rubidium-86, Ruthenium-106, Samarium-153, Scandium-46, Silver-110m, Strontium-89, Strontium-90, Sulfur-35, Technetium-99, Terbium-160, Thulium-170, Tungsten-188, Yttrium-90 and Xenon-133.
- 40. The angioplastic device of claim 37, wherein the radioactive molecule is selected from the group consisting of a radioactive DNA or an analog thereof, a radioactive RNA, a radioactive nucleotide, a radioactive oligonucleotide, radioactive H_2PO_4 , radioactive diethylenetriaminepentaacetic acid, and a radioactive polyanionic complex.
- 41. The angioplastic device of claim 37, wherein the radioactive molecule is a radioactive oligonucleotide.
- 42. The angioplastic device of claim 37, wherein the oligonucleotide is a 10- to 30-mer oligonucleotide.
- 43. The angioplastic device of claim 37, wherein the oligonucleotide is a 8- to 20-mer oligonucleotide.

- 44. The angioplastic device of claim 37, wherein the oligonucleotide is a 15-mer oligonucleotide.
- 45. The angioplastic device of claim 37, wherein the radioactive molecule is selected from the group consisting of radioactive conjugated polypeptides, radioactive cationic peptides, radioactive dextran, radioactive polyamines and radioactive chitosan.
- 46. The angioplastic device of claim 37, wherein the angioplastic device is a stent or a microcatheter wire.
- 47. A method for preventing restenosis in a coronary and/or peripheral artery comprising implanting an angioplastic device as defined in claim 37 at a site of potential restenosis in a coronary and/or peripheral artery of a patient in need of such a treatment.
- 48. The method of claim 20, wherein before the step of applying an electric potential difference, the surface of the angioplastic device is functionnalized for molecule coating.
- 49. The method of claim 48, wherein the angioplastic device is functionnalized with a diazonium treatment.

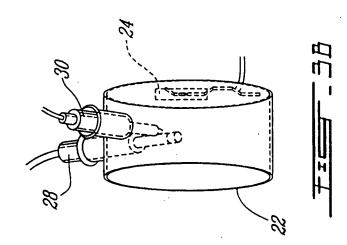
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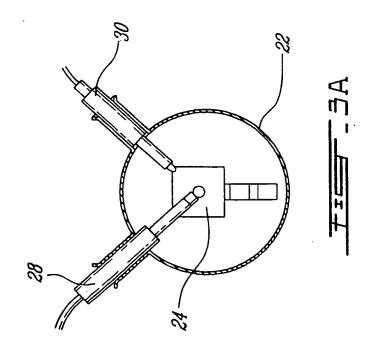
50. Use of an angioplastic device as defined in claim 14, 37, 38, 39, 40, 41, 42, 43, 44, 45 or 46 for preventing restenosis in a coronary and/or peripheral artery.

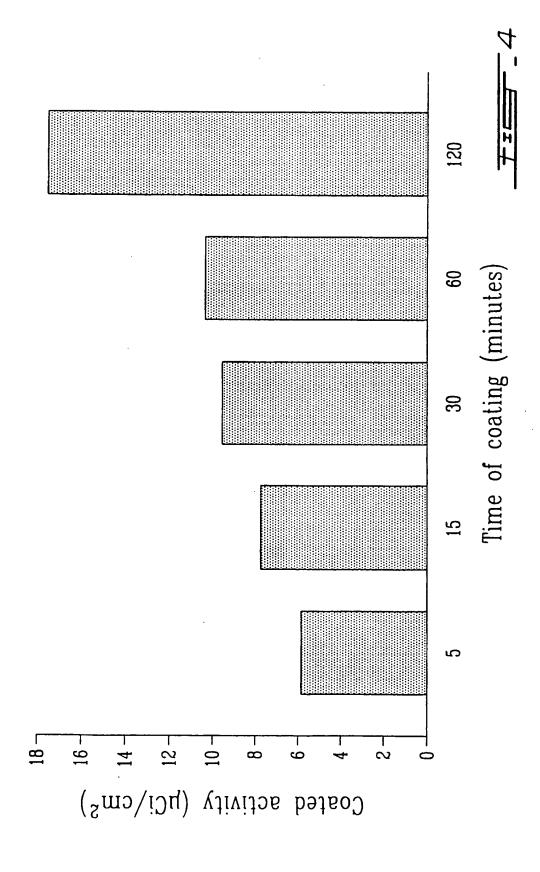


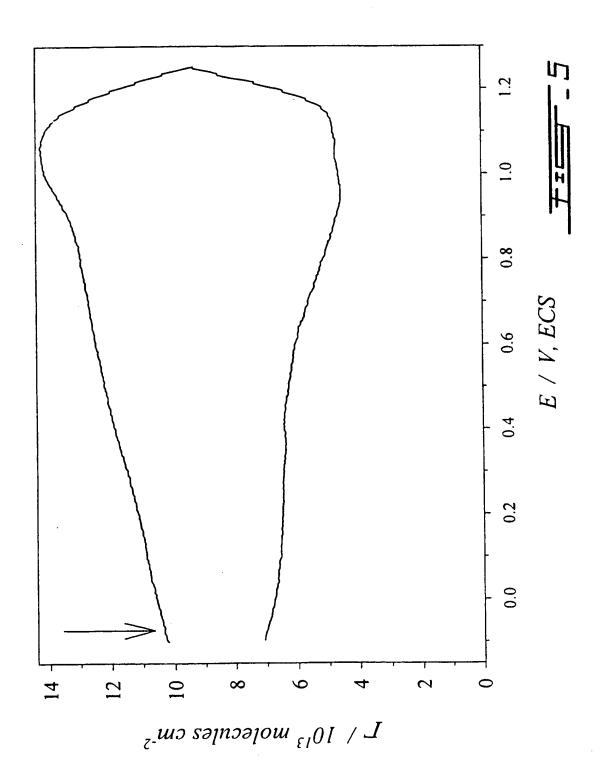


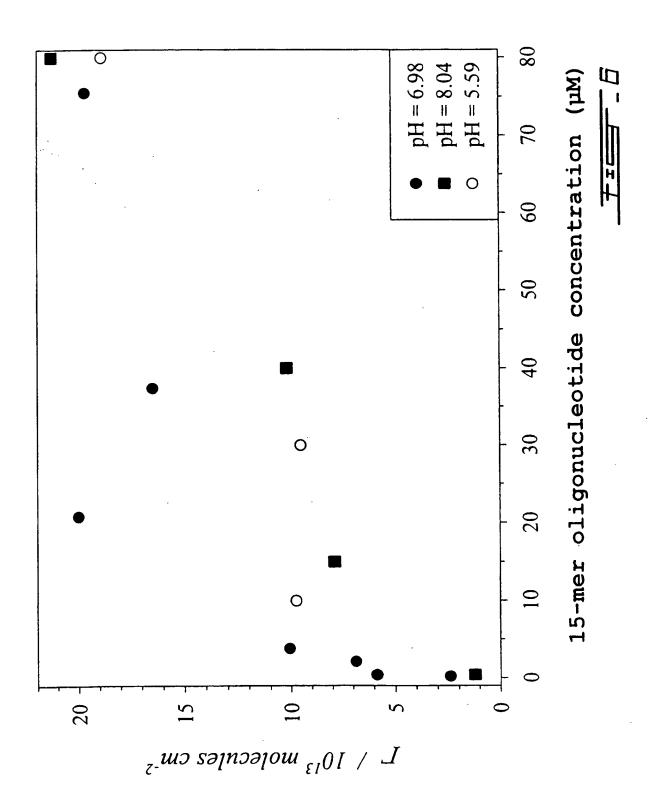
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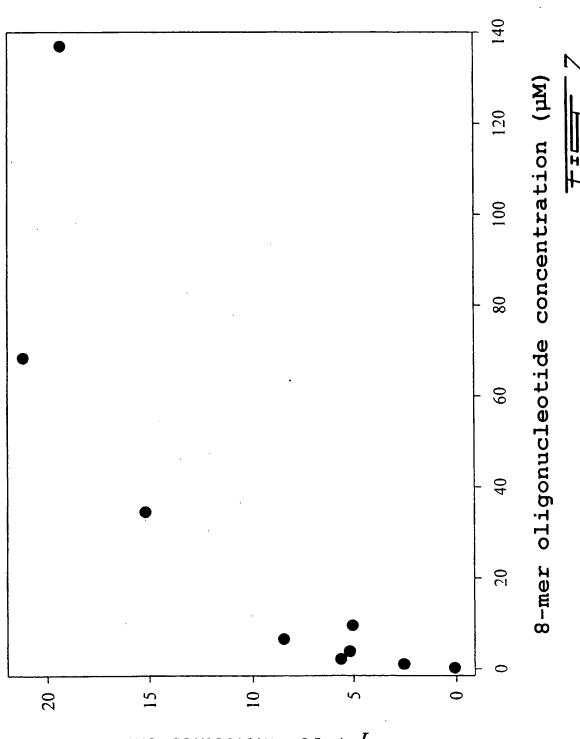




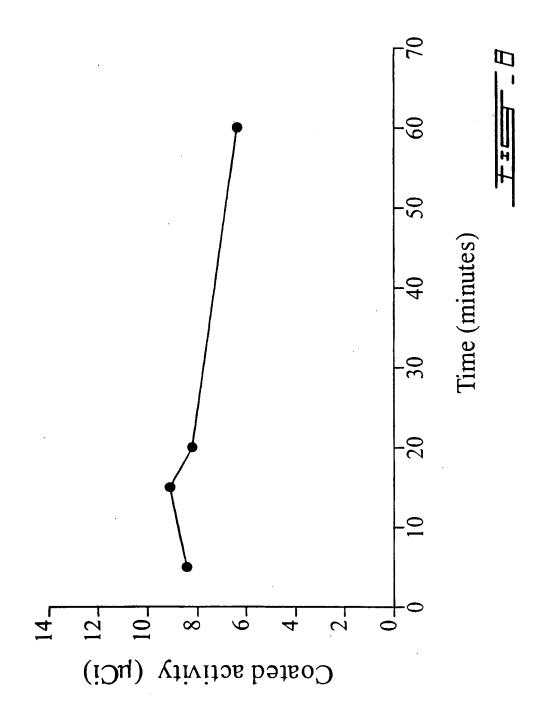


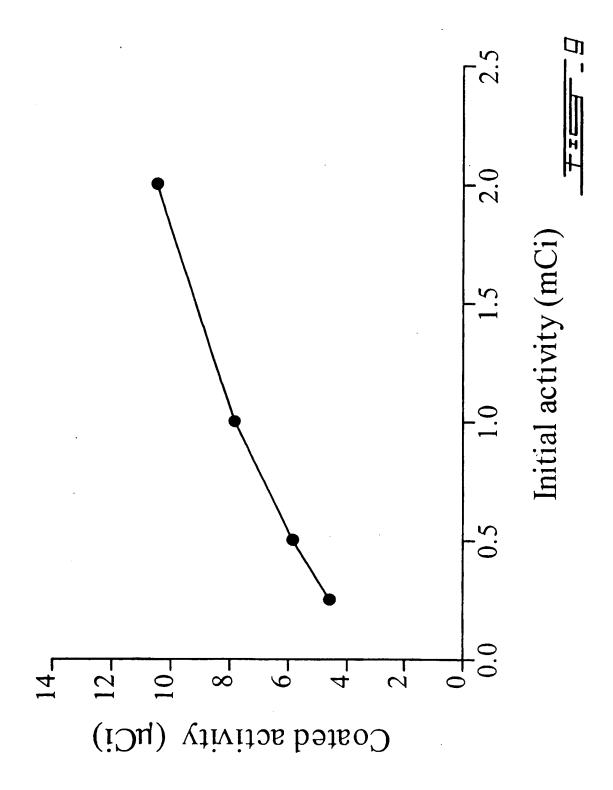


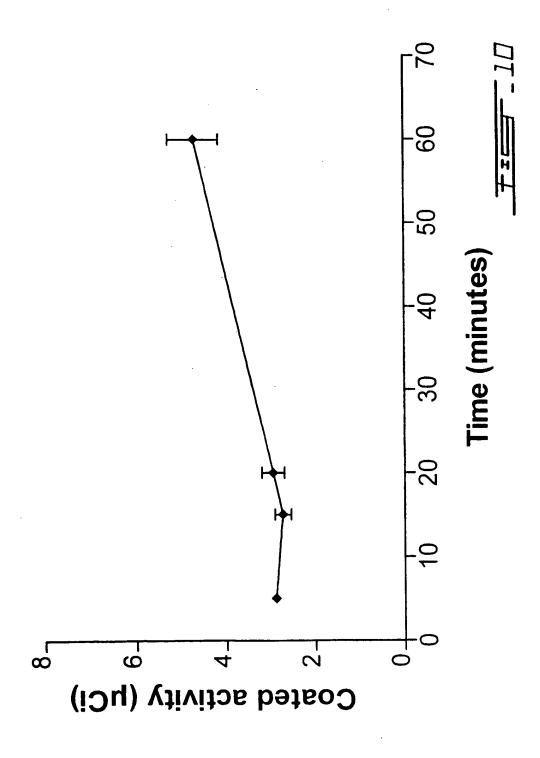


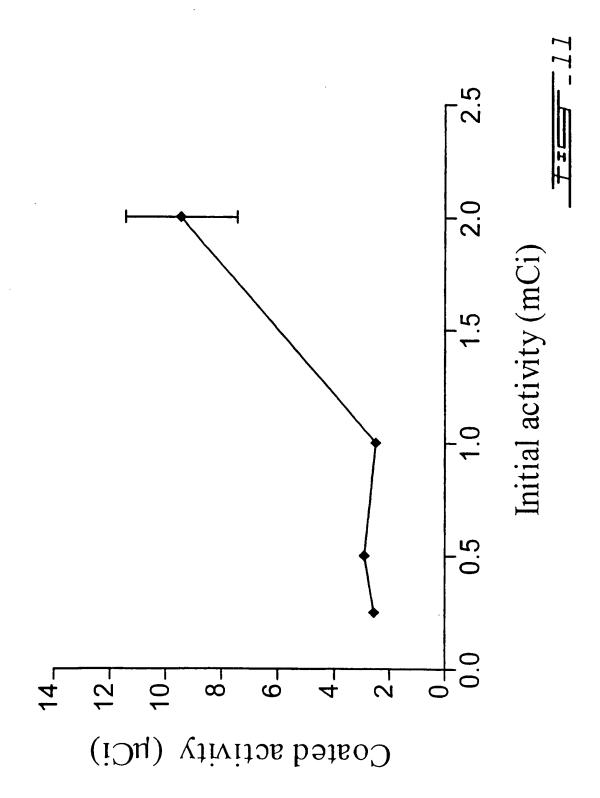


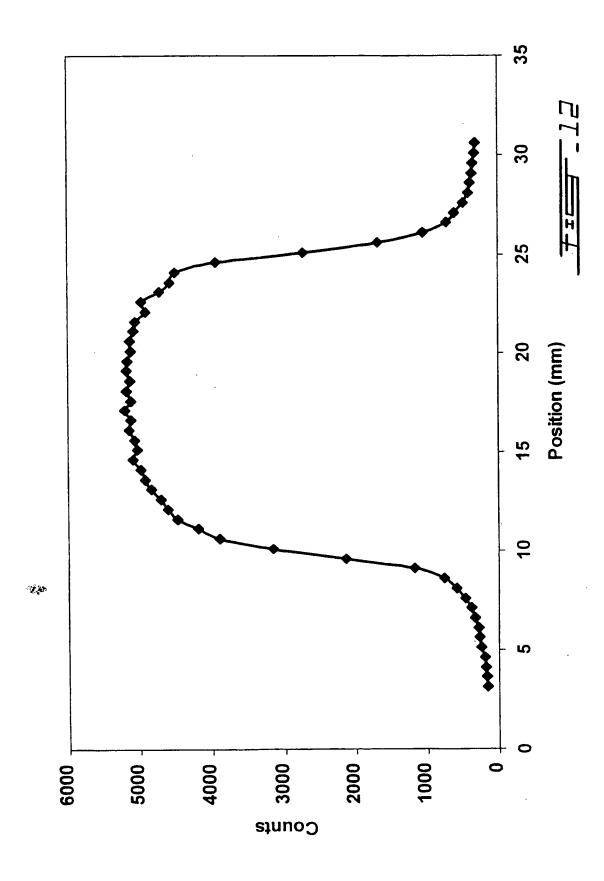
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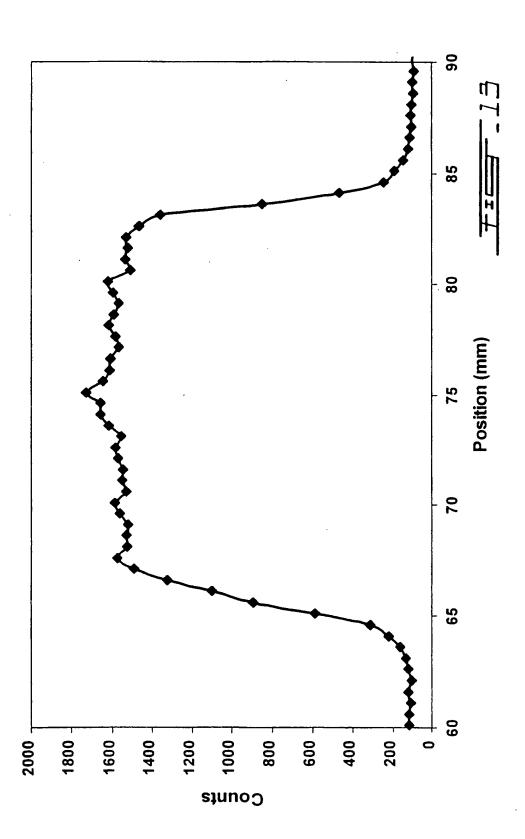


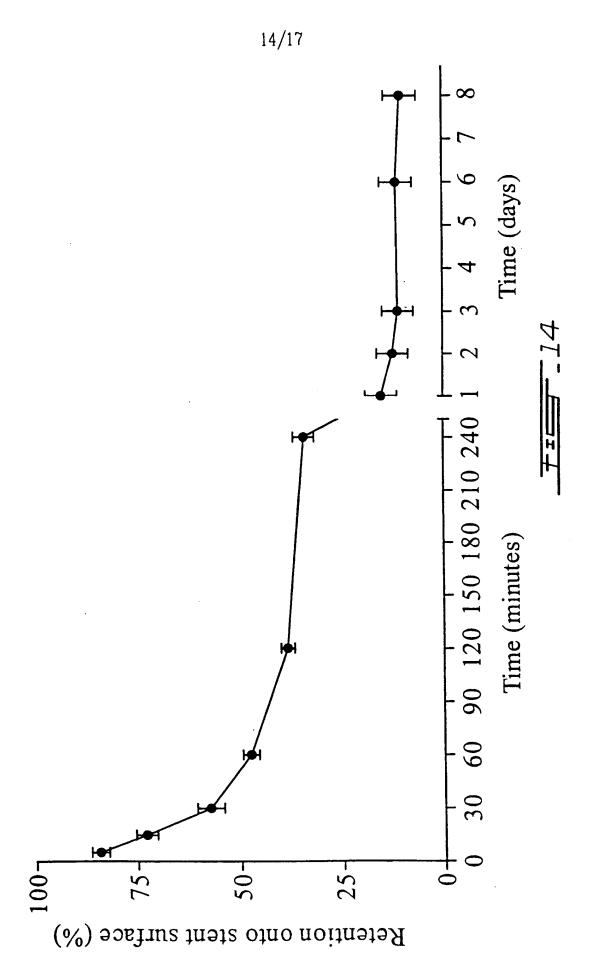




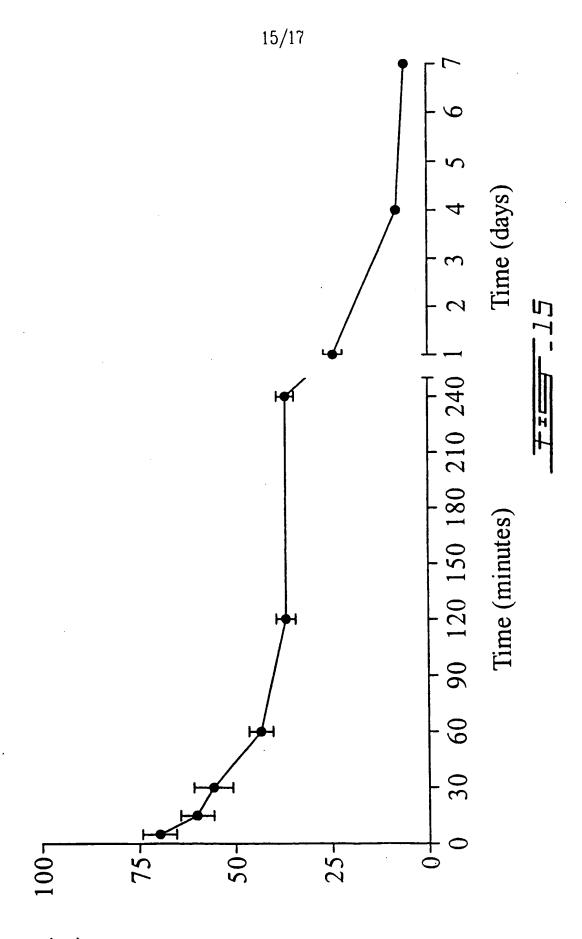






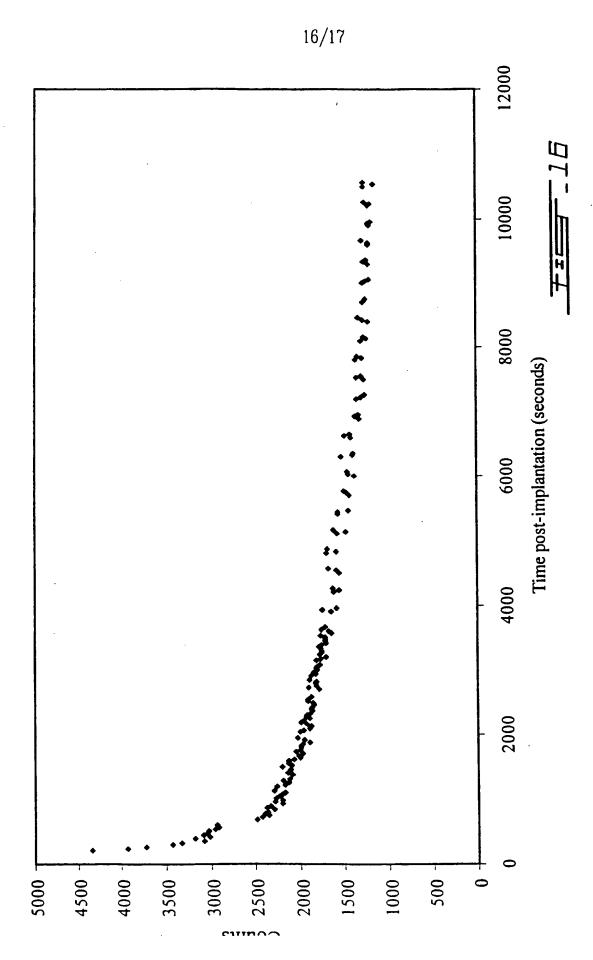


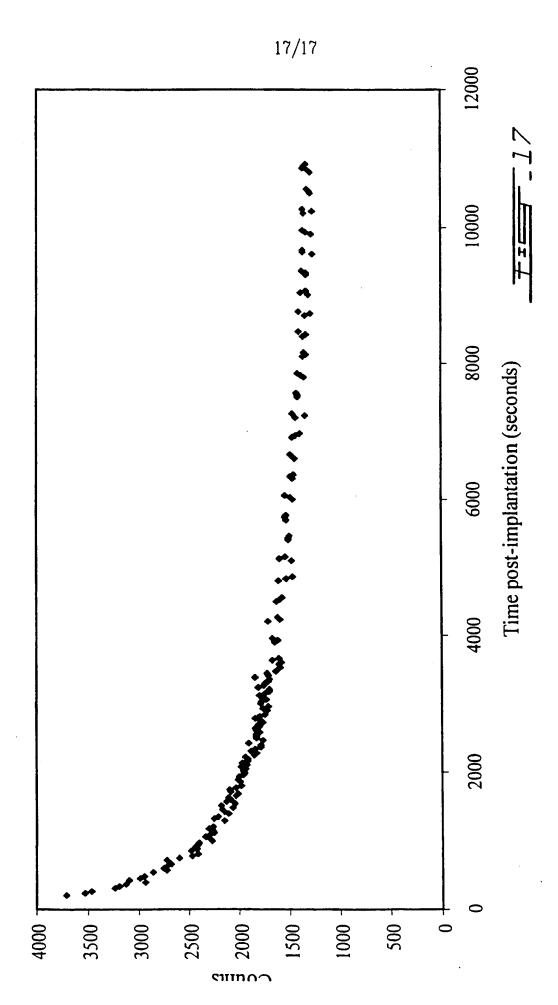
WO 01/14617



Retention onto stent surface (%)

PCT/CA00/00974





Interr nai Application No PCT/CA 00/00974

A. CLASSIFICATION OF SUBJECT MATTER
IPC 7 C25D13/04 C09D5/44
A61L31/08

C25D9/00

A61F2/06

A61M29/02

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

IPC 7 C25D C09D A61F A61M A61K A61L

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EPO-Internal, WPI Data, PAJ

C. DOCUM	ENTS CONSIDERED TO BE RELEVANT		
Category °	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to daim No.	
x	HAFELI U O ET AL: "Electrodeposition of radioactive rhenium onto stents to prevent restenosis" BIOMATERIALS, GB, ELSEVIER SCIENCE PUBLISHERS BV., BARKING, vol. 19, no. 10, 1 May 1998 (1998-05-01), pages 925-933, XP004124453 ISSN: 0142-9612 cited in the application the whole document	1,2,4-7, 9-23,29, 31-39, 46,48	
X	DE 197 24 223 C (SCHERING AG) 24 December 1998 (1998-12-24)	1,4-7, 9-11, 14-16, 19-23, 31-39,46	
••	claims 1-5 -/	31 33,10	

Further documents are listed in the continuation of box C.	Patent family members are listed in annex.
Special categories of cited documents: 'A' document defining the general state of the art which is not considered to be of particular relevance 'E' earlier document but published on or after the international filing date 'L' document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) 'O' document referring to an oral disclosure, use, exhibition or other means 'P' document published prior to the international filing date but later than the priority date claimed	 *T* later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention *X* document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone *Y* document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art. *&* document member of the same patent family
Date of the actual completion of the international search 24 November 2000	Date of mailing of the international search report 0.8, 12, 2000
Name and mailing address of the ISA European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl,	Authorized officer Hillebrand, G

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Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	WO 99 02195 A (IMPLANT SCIENCES CORP ;ARMINI ANTHONY J (US)) 21 January 1999 (1999-01-21)	1,4-7, 9-11, 14-16, 19,23, 29, 31-33, 36-39,46
	claims 20,23,26,27	
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ational application No. PCT/CA 00/00974

Box I	Observations where certain claims were found unsearchable (Continuation of item 1 of first sheet)
This Inte	ernational Search Report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:
1. χ	Claims Nos.: 47, 50 because they relate to subject matter not required to be searched by this Authority, namely:
	Rule 39.1(iv) PCT - Method for treatment of the human or animal body by therapy
2.	Claims Nos.: because they relate to parts of the International Application that do not comply with the prescribed requirements to such an extent that no meaningful International Search can be carried out, specifically:
3.	Claims Nos.: because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).
Box II	Observations where unity of invention is lacking (Continuation of Item 2 of first sheet)
This Int	ernational Searching Authority found multiple inventions in this international application, as follows:
1.	As all required additional search fees were timely paid by the applicant, this International Search Report covers all searchable claims.
2.	As all searchable claims could be searched without effort justifying an additional fee, this Authority did not invite payment of any additional fee.
3.	As only some of the required additional search fees were timely paid by the applicant, this International Search Report covers only those claims for which fees were paid, specifically claims Nos.:
4. [No required additional search fees were timely paid by the applicant. Consequently, this International Search Report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.:
	The additional areas for a second and his the applicable protect
Rema	The additional search fees were accompanied by the applicant's protest.
	No protest accompanied the payment of additional search fees.

ormation on patent family members

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